

Calculation of optical modes for chalcogenide compounds Sn₂P₂X₆ (X=S, Se)

V.Yu. Klevets, N.D. Savchenko, A.G. Slivka, A.I. Susla, V.Yu. Bihanych

Uzhhorod National University, 88000, Uzhhorod, Voloshin Str., 54, Ukraine

e-mail: klevetsvyu@gmail.com

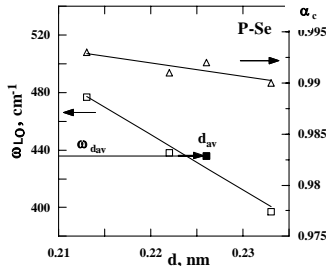
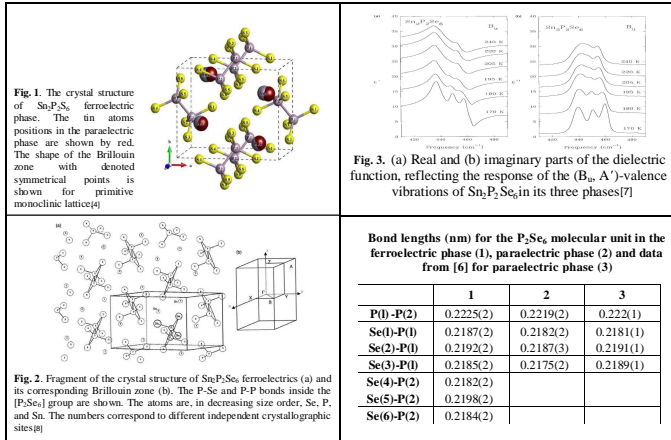


Fig. 4. Calculated transverse optical mode frequencies and covalency versus interatomic distance for P-Se. Open squares show interatomic distances P-Se₁ (0.213 nm), P-Se₂ (0.224 nm), P-Se₃ (0.233 nm).

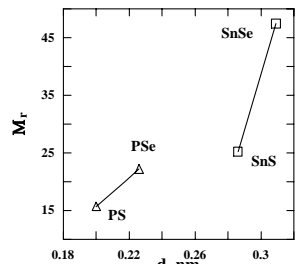


Fig. 8. Correlation between the reduced mass and interatomic distance for different chalcogenide compounds

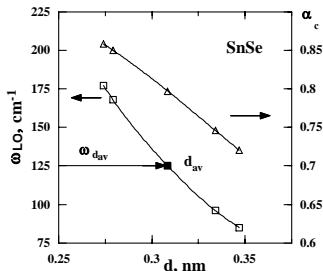


Fig. 5. Interatomic distance dependence of transverse optical mode frequencies and covalency for SnSe; d₁=(0.254 nm), d₂=(0.2567 nm), d₃=(0.334 nm), d₄=(0.347 nm)

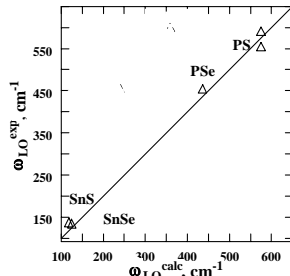


Fig. 9. Correlation between calculated and experimental values of longitudinal optical mode frequencies for chalcogenide compounds

Computational procedure and Results

Transverse optical and acoustic mode frequencies:

$$\omega_{TO,TA}^2 = \frac{\omega_{LO}^2}{2} \left(1 \pm \sqrt{\cos^2 \left(\frac{qa}{4} \right) + 0,44 \sin^2 \left(\frac{qa}{4} \right)} \right);$$

$$\omega_0^2 = \frac{64(1+\lambda)V_s^2\alpha_c^2}{3M_1d^2}; \quad \alpha_c = \frac{V_s}{\sqrt{V_2^2 + V_3^2}}; \quad V_s = \frac{\eta\hbar^2}{md^2},$$

where d – interatomic distance; α_c – covalency; M_1 – energy equivalent of the reduced atomic mass; V_2 and V_3 – covalent and ionic bond energy, X=S, Se.

Sn-X	P-X
$V_s = \frac{\epsilon_{\text{non}} - \epsilon_{\text{par}}}{2}$	$V_s = \frac{\epsilon_{\text{par}} - \epsilon_{\text{fer}}}{2}$
$\eta_1 = \eta_{\text{av}} + 2\sqrt{3}\eta_{\text{par}} + 3\eta_{\text{fer}} = 3.22$	$\eta_2 = 2\sqrt{3}\eta_{\text{par}} + 3\eta_{\text{fer}} = 2.89$
$\lambda_1 = \frac{\sqrt{3}\eta_{\text{av}} + 3\eta_{\text{par}} - 3\eta_{\text{fer}}}{-\eta_{\text{av}} + 2\sqrt{3}\eta_{\text{par}} + 3\eta_{\text{fer}}} = 0.854$	$\lambda_2 = \frac{3\eta_{\text{par}} - 3\eta_{\text{fer}}}{-\eta_{\text{av}} + 2\sqrt{3}\eta_{\text{par}} + 3\eta_{\text{fer}}} = 0.663$
$\eta_{\text{par}} = 1.42, \eta_{\text{fer}} = 2.22, \eta_{\text{fer}} = -1.32, \eta_{\text{par}} = -0.63$	

Table 1
Atomic terms and elemental atomic masses (M)

	Sn	P	S	Se
ϵ_{par} , eV	6.76	9.54	11.60	10.68
ϵ_{fer} , eV	13.04	19.22	24.02	22.86
ϵ_{S} , eV	8.33	9.54	14.71	13.73
M	118.7	30.97	32.06	78.96

Table 2

Experimental and calculated parameters for binaries

Parameters	Compound			
	PS	PSe	SnS	SnSe
d, nm	0.200	0.226	0.299	0.309
V _s , eV	5.51	4.44	3.44	2.59
V _{av} , eV	1.03	0.57	2.42	1.96
(V ₂ ² +V ₃ ²) ^{1/2} , eV	5.43	4.48	4.21	3.25
α_c	0.92	0.99	0.82	0.80
M _r	15.72	22.24	25.24	47.42
$\omega_{LO}^{\text{calc}}$, cm ⁻¹	575	436	118	125
ω_{LO}^{exp} , cm ⁻¹	555-591	454	137	134

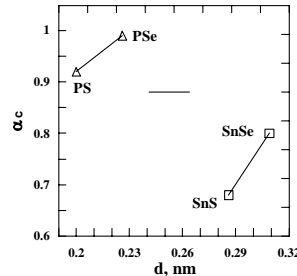


Fig. 6. Correlation between covalency and interatomic distance for different chalcogenide compounds

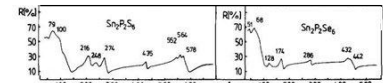


Fig. 7. FIR reflection spectra of layered hexachalcogenopolythiophosphates (pressed pellets, Bruker IFS 114) [3]

References

- [1] Harrison W. A., Elementary Electronic Structure. New Jersey, London, Singapore, Shanghai, Hong Kong, Taipei, Chennai: World Scientific Publishing Co. 2004.
- [2] Kliche G. J. Sol. State Chem., 1984, 51, pp.118-126.
- [3] Zamaraita I., Svirskas S., et al. Dielectric, pyroelectric and ferroelectric properties of lead-doped Sn₂P₂S₆ crystals. Phase Transitions, 2019, v. 92, p. 500 - 507.
- [4] Glukhov K., Fedyo K., Banyas J., Vysochanskiy Y. Electronic Structure and Phase Transition in Ferroelectric Sn₂P₂S₆ Crystal. Int. J. Mol. Sci. 2012.
- [5] Miliutinovic A., Popovic Z.V., Tomic N., Devic S. Materials Science Forum, 2004, 453-454 pp. 299-304.
- [6] Voroshilov Yu.V., et al. Sov. Phys. Crystallogr., 33, 761 1988.
- [7] Eijt S., Maior M.M. J. Phys. and Chem. of Solids, 60, 631, 1999.
- [8] R.Caracas et al. Phys. Rev. B 66, 104106, 2002